

Product data sheet

1. General description

Ultrafast, dual common cathode, epitaxial rectifier diodes in a SOT78 (TO-220AB) plastic package.

2. Features and benefits

- Fast switching
- Low thermal resistance
- Soft recovery characteristic
- Low forward voltage drop
- Reverse surge capability
- High thermal cycling performance

3. Applications

• Output rectifiers in high-frequency switched-mode power supplies

4. Quick reference data

Table 1. Q	uick reference data						
Symbol	Parameter	Conditions	Values				Unit
Absolute	maximum rating						
V_{RRM}	repetitive peak reverse voltage			200			V
I _{O(AV)}	average output current	δ = 0.5; square-wave pulse; T _{mb} ≤ 119 °C; both diodes conducting; <u>Fig. 5</u> ; <u>Fig. 6</u>		10		A	
I _{FRM}	repetitive peak forward current	δ = 0.5; t _p = 25 μs; T _{mb} ≤ 119 °C; square-wave pulse; per diode		10		A	
I _{FSM}	non-repetitive peak	t _p = 10 ms; sine-wave pulse; per diode	50			А	
forward current		t_p = 8.3 ms; sine-wave pulse; per diode	55			А	
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static ch	aracteristics						
V _F	forward voltage	I _F = 5 A; T _j = 25 °C; <u>Fig. 2</u>		-	0.95	1.1	V
		I _F = 5 A; T _j = 150 °C; <u>Fig. 2</u>		-	0.8	0.895	V
		I _F = 10 A; T _j = 25 °C; <u>Fig. 2</u>		-	1.1	1.25	V
Dynamic	characteristics	· · · · · · · · · · · · · · · · · · ·					
t _{rr}	reverse recovery time	ramp recovery; I _F = 1 A; V _R = 30 V; dI _F /dt = 100 A/μs; T _j = 25 °C; <u>Fig. 3</u>		-	15	25	ns
		step recovery; when switched from $I_F = 0.5 A$ to $I_R = 1 A$; measured at $I_R = 0.25 A$		-	10	20	ns

5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	A1	anode 1	mb	
2	K	cathode	205	
3	A2	anode 2		
mb	К	mounting base; connected to cathode		K sym125

6. Ordering information

Table 3. Ordering information						
Type number	umber Package					
	Name	Description	Version			
BYQ28E-200	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78			

7. Marking

Table 4. Marking codes	
Type number	Marking codes
BYQ28E-200	BYQ28E-200

8. Limiting values

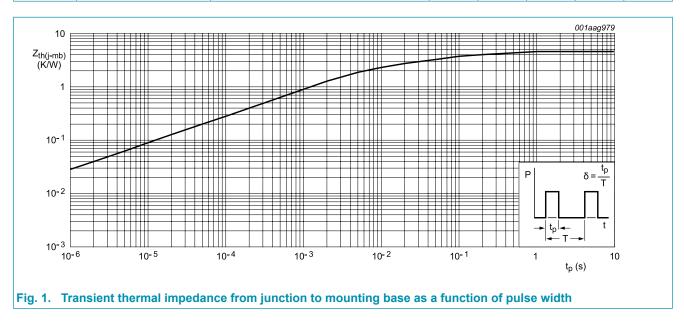
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V_{RRM}	repetitive peak reverse voltage		200	V
V_{RWM}	crest working reverse voltage		200	V
V _R	reverse voltage	δ = 1.0; square-wave pulse	200	V
I _{O(AV)}	average output current	δ = 0.5; square-wave pulse; T _{mb} ≤ 119 °C; both diodes conducting; <u>Fig. 5; Fig. 6</u>	10	A
I _{FRM}	repetitive peak forward current	δ = 0.5; t _p = 25 μs; T _{mb} ≤ 119 °C; square-wave pulse; per diode	10	A
I _{FSM}	non-repetitive peak	t_p = 10 ms; sine-wave pulse; per diode	50	A
	forward current	t_p = 8.3 ms; sine-wave pulse; per diode	55	А
I _{RM}	peak reverse recovery current	$δ = 0.001; t_p = 2 μs$	0.2	A
I _{RSM}	non-repetitive peak reverse current	t _p = 100 μs	0.2	A
T _{stg}	storage temperature		-40 to 150	°C
Tj	junction temperature		150	°C
Electrosta	tic discharge			
V_{ESD}	electrostatic discharge voltage	all pins; human body model; C = 250 pF; R = 1.5 k Ω	8	kV

9. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{\text{th(j-mb)}}$	thermal resistance from junction to	with heatsink compound; both diodes conducting	-	-	3	K/W
	mounting base	with heatsink compound; per diode; <u>Fig 1</u>	-	-	4.5	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient	in free air	-	60	-	K/W



10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics					
V _F	forward voltage	I _F = 5 A; T _j = 150 °C; <u>Fig. 2</u>	-	0.8	0.895	V
		I _F = 5 A; T _j = 25 °C; <u>Fig. 2</u>	-	0.95	1.1	V
		I _F = 10 A; T _j = 25 °C; <u>Fig. 2</u>	-	1.1	1.25	V
I _R	reverse current	V _R = 200 V	-	2	10	μA
		V _R = 200 V; T _j = 100 °C	-	0.1	0.2	mA
Dynamic	characteristics					
Q _r	recovered charge	I _F = 2 A; V _R = 30 V; dI _F /dt = 20 A/µs; T _j = 25 °C; <u>Fig. 3</u>	-	4	9	nC
t _{rr}	reverse recovery time	ramp recovery; I _F = 1 A; V _R = 30 V; dI _F /dt = 100 A/µs; T _j = 25 °C; <u>Fig. 3</u>	-	15	25	ns
		step recovery; when switched from $I_F = 0.5 A$ to $I_R = 1 A$; measured at $I_R = 0.25 A$	-	10	20	ns
I _{RM}	peak reverse recovery current	$I_F = 5 \text{ A}; V_R = 30 \text{ V}; \text{ d}I_F/\text{d}t = 50 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}; \text{ Fig. 3}$	-	0.5	0.7	A
V_{FR}	forward recovery voltage	I _F = 1 A; dI _F /dt = 10 A/μs; T _i = 25 °C; <u>Fig. 4</u>	-	1	-	V

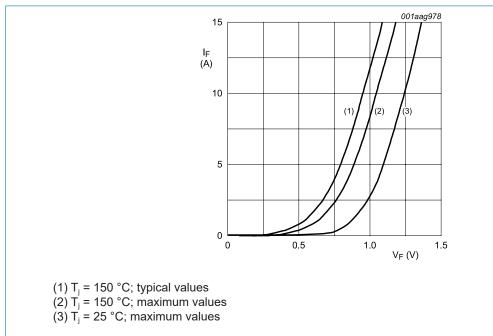
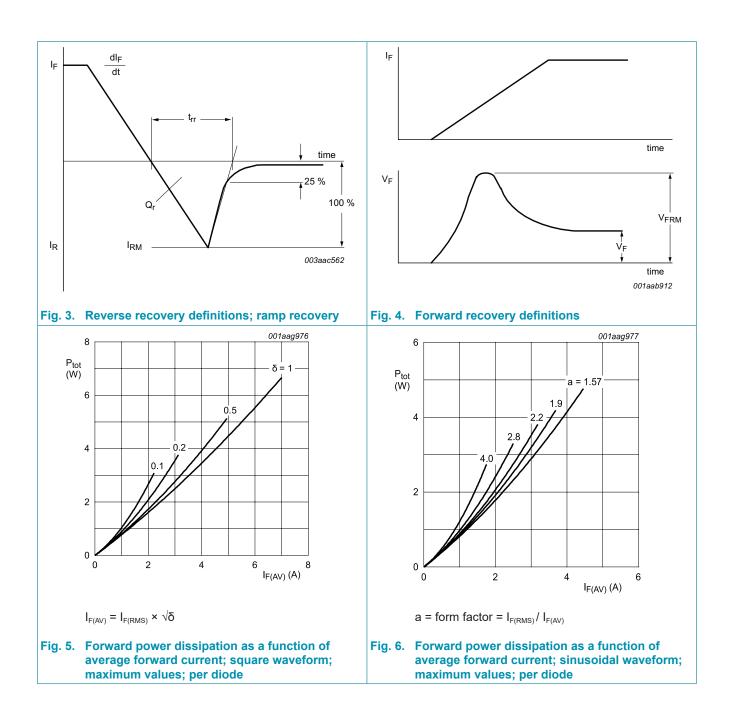


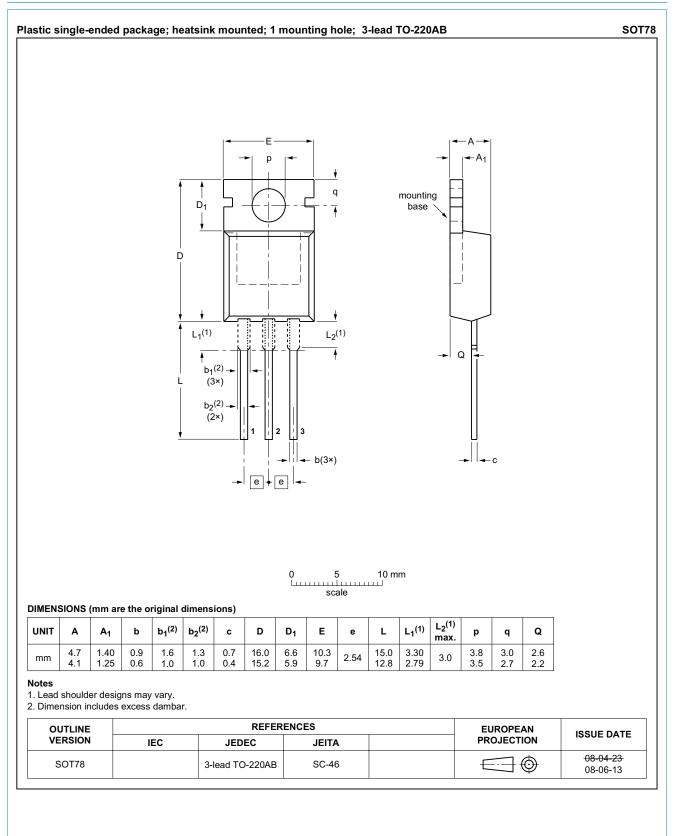
Fig. 2. Forward current as a function of forward voltage

BYQ28E-200

Rectifier diodes ultrafast, rugged



11. Package outline



12. Revision history

Table 8. Revision histor	ry						
Document ID	Release date	Data sheet status	Change notice	Supersedes			
BYQ28E-200 v.5	20180307	Product data sheet	-	BYQ28_SER_E_ED_4			
Modifications: Ch	ange from NXP version to We	eEn version					
BYQ28_SER_E_ED_4	20071205	Product data sheet	-	BYQ28E_SERIES_3			
 Modifications: The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. Legal texts have been adapted to the new company name where appropriate. Limiting values table: some parameter descriptions amended to conform to latest standards; IFRM conditions amended; VESD row added. Characteristics: Qrr changed to Qr 'recovered charge'; trr1 and trr2 changed to trr with 'ramp recovery' and 'step recovery' added to conditions. 							
BYQ28E_SERIES_3	19981001	Product specification	-	BYQ28E_SERIES_2			
BYQ28E_SERIES_2	19980701	Product specification	-	BYQ28E_SERIES_1; BYQ28EB_SERIES_1			
BYQ28E_SERIES_1; BYQ28EB_SERIES_1	19960801	Product specification	-	-			

BYQ28E-200 Rectifier diodes ultrafast, rugged

13. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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